

**PATENT APPLICATION**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of

Docket No: Q81505

Akira BANDOH, et al.

Appln. No.: 10/585,744

Group Art Unit: 2826

Confirmation No.: 1506

Examiner: Selim U AHMED

Filed: July 12, 2006

For: N-TYPE GROUP III NITRIDE SEMICONDUCTOR LAYERED STRUCTURE

**AMENDMENT UNDER 37 C.F.R. § 1.111**

**MAIL STOP AMENDMENT**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated May 13, 2009, please amend the above-identified application as follows on the accompanying pages.

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